

UF460-HC

Power MOSFET

24A, 500V N-CHANNEL POWER MOSFET

■ DESCRIPTION

The UTC **UF460-HC** is a N-channel enhancement MOSFET using UTC's advanced technology to provide the customers with perfect $R_{DS(ON)}$, high switching speed, high current capacity and low gate charge.

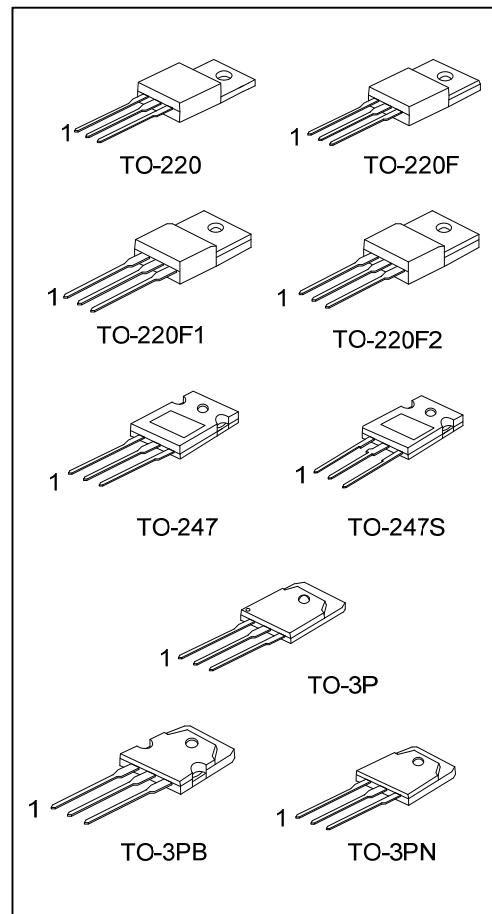
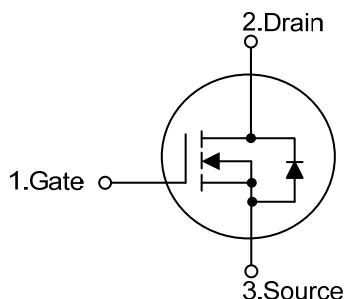
The UTC **UF460-HC** is universally applied in low voltage such as automotive, high efficiency switching for AC/DC converters and DC motor control, etc.

■ FEATURES

* $R_{DS(ON)} \leq 0.26 \Omega$ @ $V_{GS}=10V$, $I_D=12A$

* High Switching Speed

■ SYMBOL



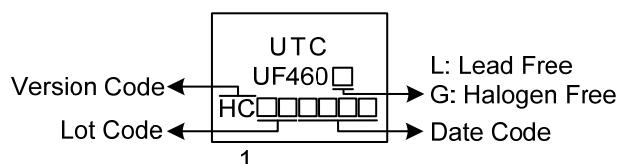
■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
UF460L-HC-TA3-T	UF460G-HC-TA3-T	TO-220	G	D	S	Tube
UF460L-HC-TF1-T	UF460G-HC-TF1-T	TO-220F1	G	D	S	Tube
UF460L-HC-TF2-T	UF460G-HC-TF2-T	TO-220F2	G	D	S	Tube
UF460L-HC-TF3-T	UF460G-HC-TF3-T	TO-220F	G	D	S	Tube
UF460L-HC-T3P-T	UF460G-HC-T3P-T	TO-3P	G	D	S	Tube
UF460L-HC-T3B-T	UF460G-HC-T3B-T	TO-3PB	G	D	S	Tube
UF460L-HC-T3N-T	UF460G-HC-T3N-T	TO-3PN	G	D	S	Tube
UF460L-HC-T47-T	UF460G-HC-T47-T	TO-247	G	D	S	Tube
UF460L-HC-T47S-T	UF460G-HC-T47S-T	TO-247S	G	D	S	Tube

Note: Pin Assignment: G: Gate D: Drain S: Source

 UF460G-HC-TA3-T	(1) T: Tube (2) TA3: TO-220, TF1: TO-220F1, TF2: TO-220F2, TF3: TO-220F, T3P: TO-3P, T3B: TO-3PB, T3N: TO-3PN, T47: TO-247, T47S: TO-247S (3) Version HC (4) G: Halogen Free and Lead Free, L: Lead Free
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■ MARKING



■ ABSOLUTE MAXIMUM RATINGS ($T_c=25^\circ\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	500	V
Gate-Source Voltage		V_{GSS}	± 30	V
Continuous Drain Current	Continuous	I_D	24	A
	Pulsed	I_{DM}	48	A
Single Pulsed Avalanche Energy		E_{AS}	1560	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	1.4	V/ns
Power Dissipation	TO-220	P_D	210	W
	TO-220F/TO-220F1		44	W
	TO-220F2		240	W
	TO-247/TO-247S		250	W
	TO-3P/TO-3PB			
	TO-3PN			
Junction Temperature	T_J		+150	$^\circ\text{C}$
Storage Temperature	T_{STG}		-55 ~ +150	$^\circ\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating: Pulse width limited by maximum junction temperature.

3. $L = 30\text{mH}$, $I_{AS} = 10.2\text{A}$, $V_{DD} = 50\text{V}$, $R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$

4. $I_{SD} \leq 24\text{A}$, $di/dt \leq 200\text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, Starting $T_J = 25^\circ\text{C}$

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	TO-220/TO-220F	θ_{JA}	62.5	$^\circ\text{C/W}$
	TO-220F1/TO-220F2		50	$^\circ\text{C/W}$
	TO-247/TO-247S		40	$^\circ\text{C/W}$
	TO-3P/TO-3PB			
	TO-3PN			
Junction to Case	TO-220	θ_{JC}	0.59	$^\circ\text{C/W}$
	TO-220F/TO-220F1		2.84	$^\circ\text{C/W}$
	TO-220F2		0.52	$^\circ\text{C/W}$
	TO-247/TO-247S			
	TO-3P/TO-3PB			
	TO-3PN		0.5	$^\circ\text{C/W}$

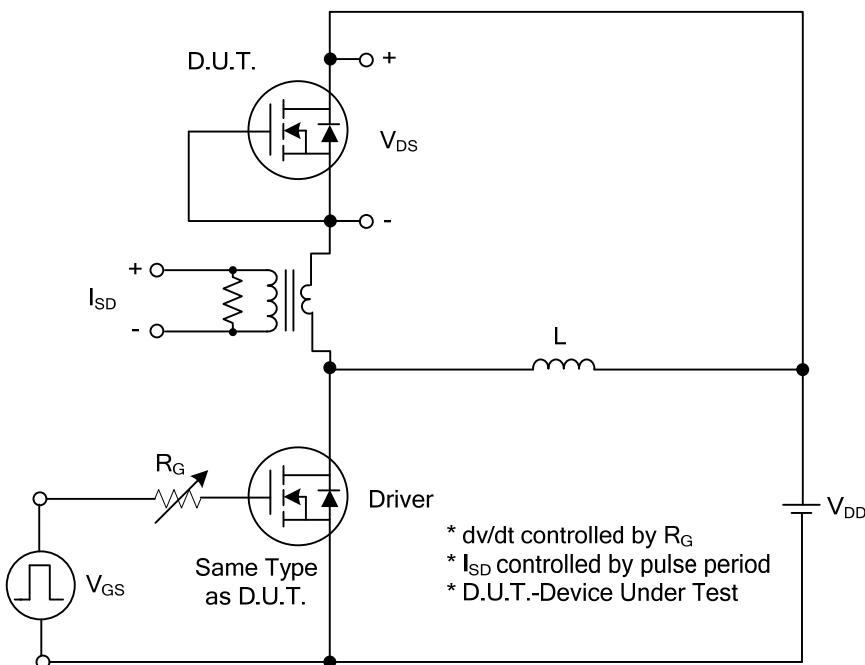
■ ELECTRICAL CHARACTERISTICS ($T_J=25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	$I_D=250\mu\text{A}, V_{GS}=0\text{V}$	500			V
Drain-Source Leakage Current	I_{DSS}	$V_{DS}=500\text{V}, V_{GS}=0\text{V}$		10		μA
Gate-Source Leakage Current	Forward	$V_{GS}=+30\text{V}, V_{DS}=0\text{V}$			+100	nA
	Reverse	$V_{GS}=-30\text{V}, V_{DS}=0\text{V}$			-100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(\text{TH})}$	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	2.0		4.0	V
Static Drain-Source On-State Resistance	$R_{DS(\text{ON})}$	$V_{GS}=10\text{V}, I_D=12\text{A}$			0.26	Ω
DYNAMIC PARAMETERS						
Input Capacitance	C_{ISS}	$V_{GS}=0\text{V}, V_{DS}=25\text{V}, f=1.0\text{MHz}$		3240		pF
Output Capacitance	C_{OSS}			355		pF
Reverse Transfer Capacitance	C_{RSS}			31		pF
SWITCHING PARAMETERS						
Total Gate Charge	Q_G	$V_{DS}=400\text{V}, V_{GS}=10\text{V}, I_D=24\text{A}$ (Note 1, 2)		100		nC
Gate to Source Charge	Q_{GS}			25		nC
Gate to Drain Charge	Q_{GD}			40		nC
Turn-ON Delay Time	$t_{D(\text{ON})}$	$V_{DD}=100\text{V}, V_{GS}=10\text{V}, I_D=24\text{A}, R_G=25\Omega$ (Note 1, 2)		48		ns
Rise Time	t_R			36		ns
Turn-OFF Delay Time	$t_{D(\text{OFF})}$			240		ns
Fall-Time	t_F			58		ns
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS						
Maximum Body-Diode Continuous Current	I_S				24	A
Maximum Body-Diode Pulsed Current	I_{SM}				48	A
Drain-Source Diode Forward Voltage	V_{SD}	$I_S=24\text{A}, V_{GS}=0\text{V}$			1.4	V
Body Diode Reverse Recovery Time	t_{rr}	$I_S=24\text{A}, V_{GS}=0\text{V}, dI_F/dt=100\text{A}/\mu\text{s}$		460		ns
Reverse Recovery Charge	Q_{rr}	(Note 1)		7.6		μC

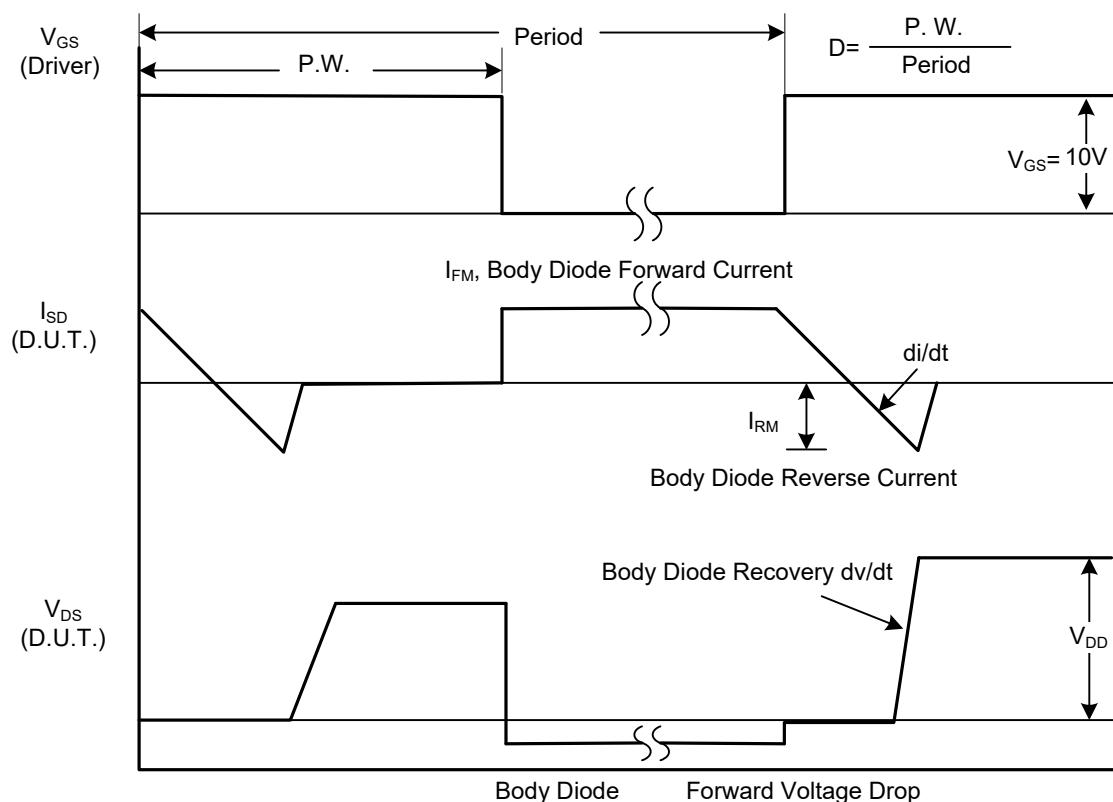
Notes: 1. Pulse Test: Pulse width $\leq 300\mu\text{s}$, Duty cycle $\leq 2\%$.

2. Essentially independent of operating temperature.

■ TEST CIRCUITS AND WAVEFORMS

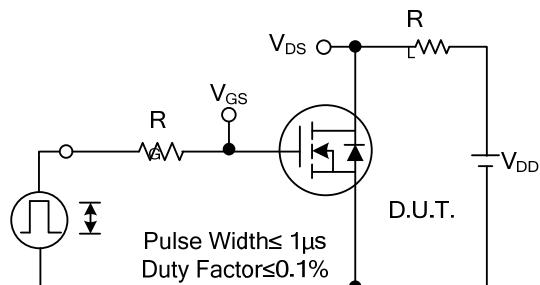


Peak Diode Recovery dv/dt Test Circuit

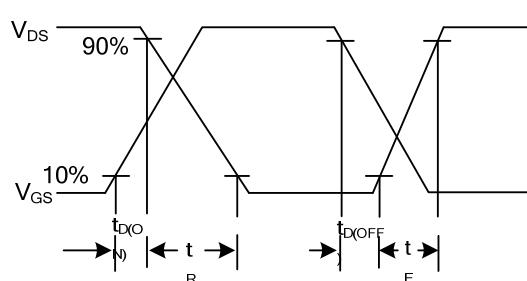


Peak Diode Recovery dv/dt Waveforms

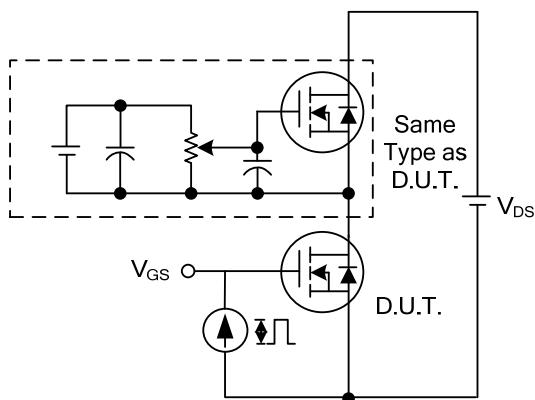
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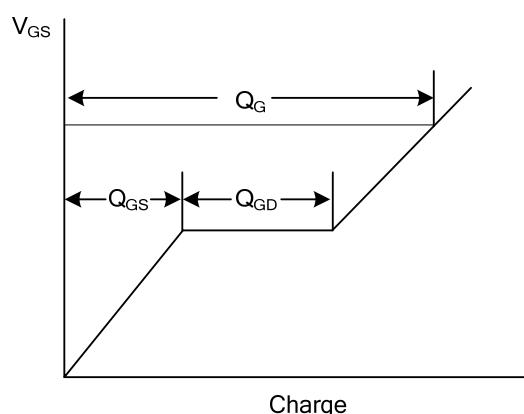
Switching Test Circuit



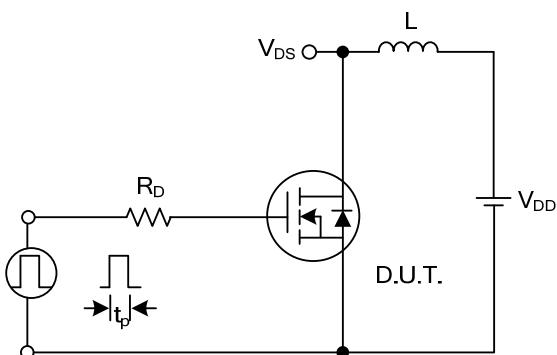
Switching Waveforms



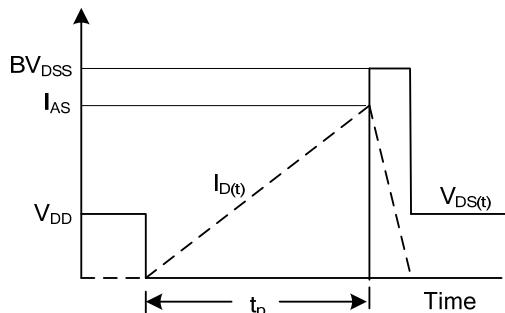
Gate Charge Test Circuit



Gate Charge Waveform

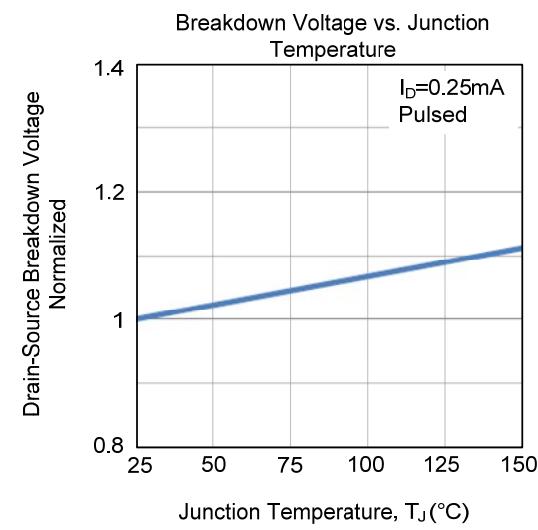
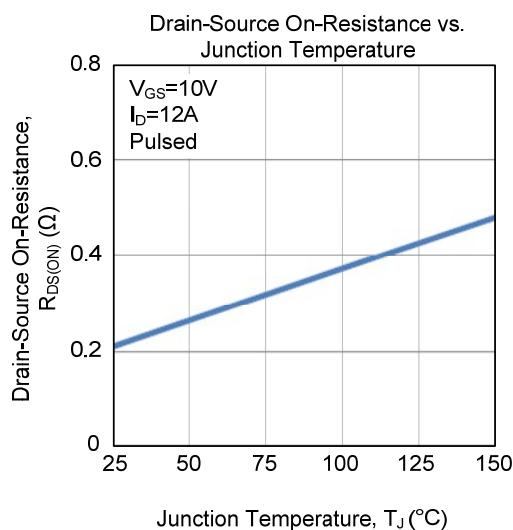
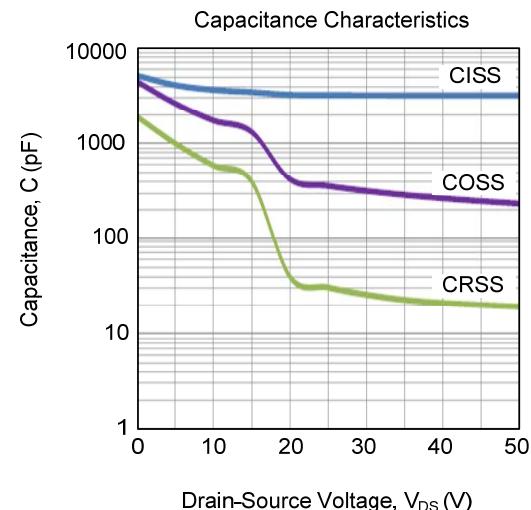
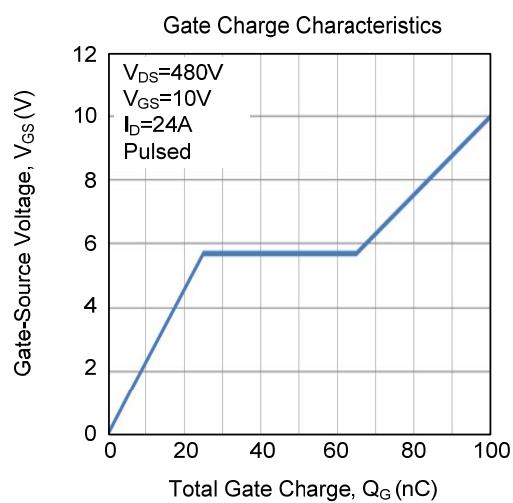
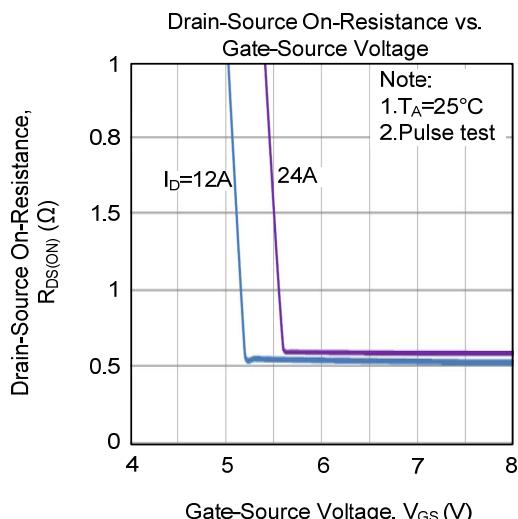
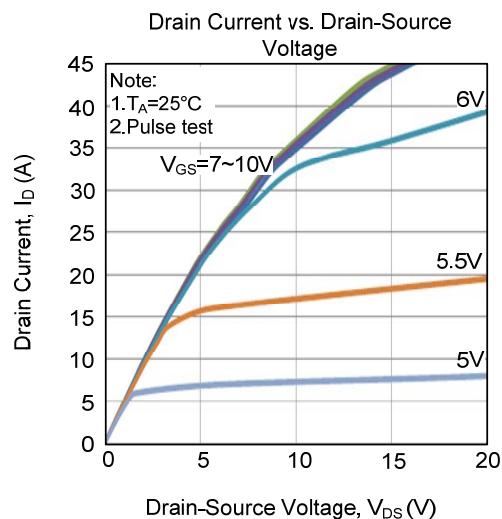


Unclamped Inductive Switching Test Circuit

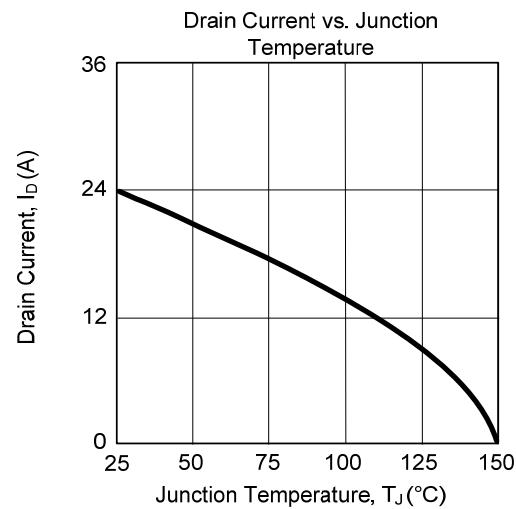
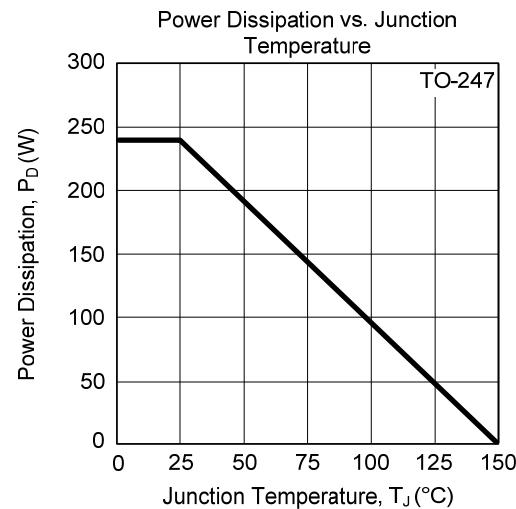
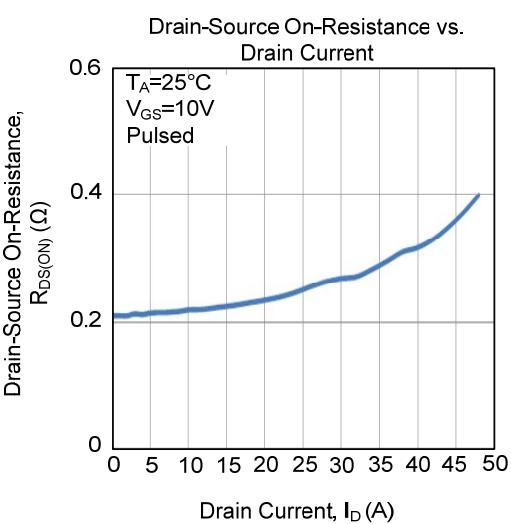
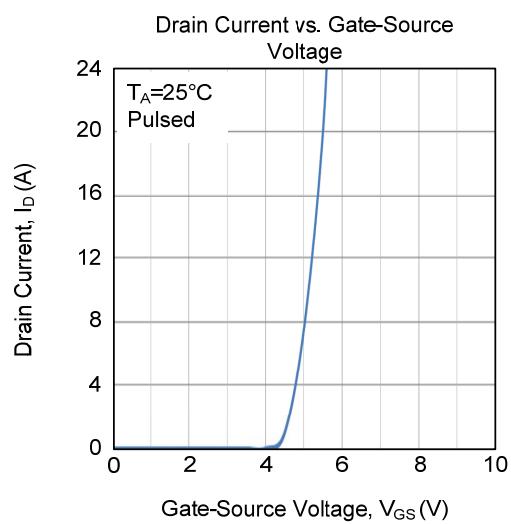
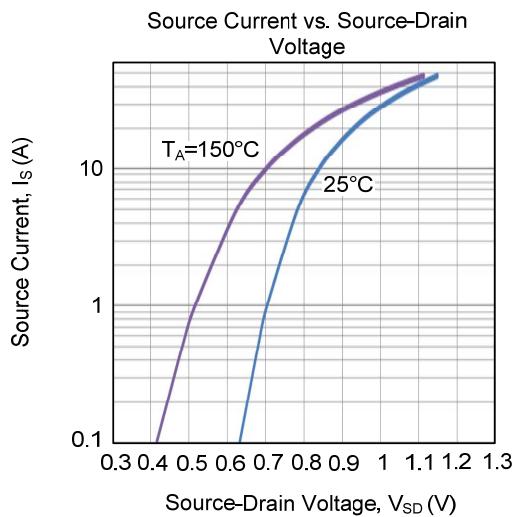
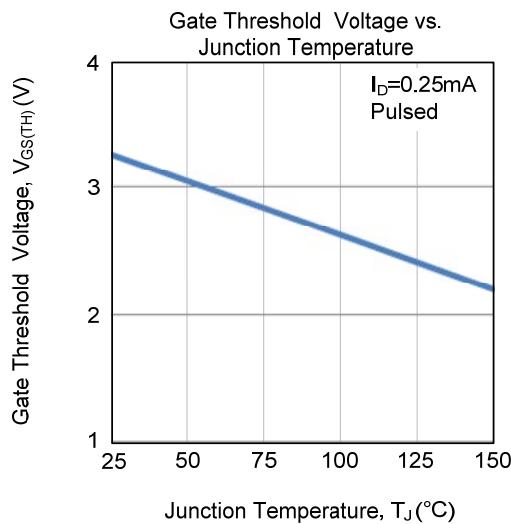


Unclamped Inductive Switching Waveforms

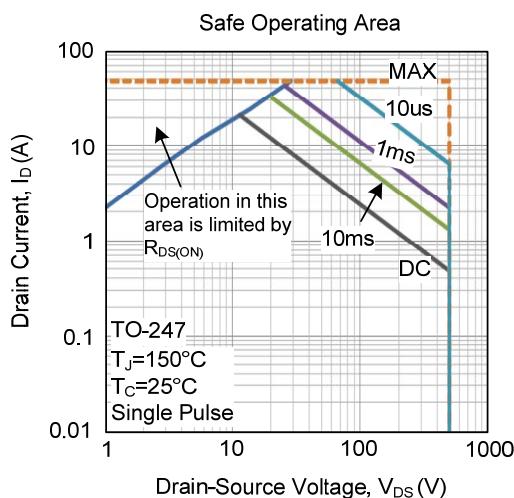
■ TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS (Cont.)



■ TYPICAL CHARACTERISTICS (Cont.)



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